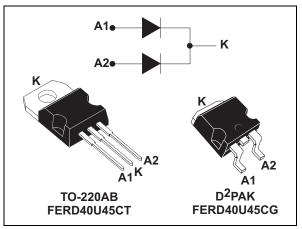


FERD40U45C

Field effect rectifier

Datasheet - production data



Features

- ST advanced rectifier process
- Stable leakage current over reverse voltage
- Low forward voltage drop
- High frequency operation

Description

This dual rectifier is based on a proprietary technology that achieves the best in class $V_{\rm F}/I_{\rm R}$ for a given silicon surface.

Packaged in TO-220AB, and D²PAK, this device is intended to be used in switch mode power supplies, or automotive applications

Table 1. Device summary

I _{F(AV)}	2 x 20 A
V _{RRM}	45 V
V _F (typ)	0.31 V

This is information on a product in full production.

1 Characteristics

Table 2. Absolute ratings (limiting values, per diode at 25° C, unless otherwise stated)

Symbol	Para	Value	Unit		
V _{RRM}	Repetitive peak reverse voltage			45	V
I _{F(RMS)}	Forward rms current			40	А
I _{F(AV)}	Average forward current, $\delta = 0.5$	T _c =150° C T _c =145° C	Per diode Per device	20 40	A
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		275	А	
T _{stg}	Storage temperature range	-65 to + 175	°C		
	Maximum operating junction	TO-220AB, D ² PA	ĸ	175	
Тj	temperature ⁽¹⁾	,	D ² PAK (DC forward current without reverse bias, t = 1 hour)		°C

1. $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistances

Symbol	Parameter	Parameter			
R _{th (j-c)}	Junction to case	Per diode Total	1.6 1.1	°C/W	
R _{th(c)}	Coupling		0.5	°C/W	

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j}(\text{diode 1}) = P(\text{diode1}) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode2}) \times R_{th(c)}.$

Table 4. Static	electrical	characteristics	(per (diode)	

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25° C	\/_ _ \/			1800	μA
'R'	Reverse leakage current	T _j = 125° C	$V_R = V_{RRM}$		50	100	mA
	Forward voltage drop $\begin{array}{c} T_{j} = 25^{\circ} \text{ C} \\ T_{j} = 125^{\circ} \text{ C} \\ T_{j} = 25^{\circ} \text{ C} \\ \end{array} \qquad I_{F} = 10 \text{ A} \\ I_{F} $	T _j = 25° C	10.0		0.35	0.385	
V _F ⁽²⁾		T _j = 125° C	F = 10 A		0.31	0.34	V
VF`			0.42	0.46	v		
		T _j = 125° C	I _F = 20 A		0.42	0.46	

1. Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$

2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.28 \text{ x } I_{F(AV)} + 0.009 I_{F}^{2}(RMS)$$



Figure 1. Average forward power dissipation versus average forward current (per diode)

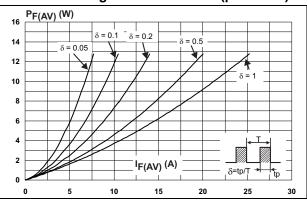


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

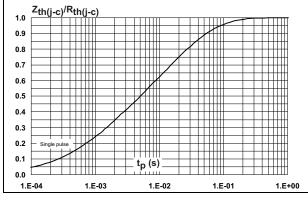


Figure 5. Junction capacitance versus reverse voltage applied (typical values, per diode)

Figure 2. Average forward current versus ambient temperature (δ = 0.5, per diode)

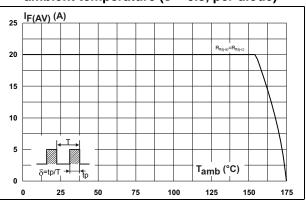


Figure 4. Reverse leakage current versus reverse voltage applied (typical values, per diode)

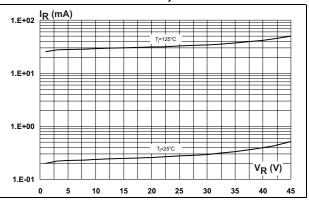
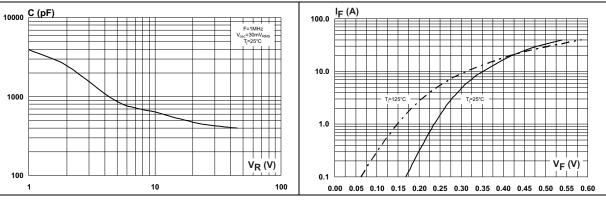


Figure 6. Forward voltage drop versus forward current (typical values, per diode)



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80	R _{th(j}	-a) (°0	C/W)						
70				Epox	y printed er thickn	circuit bo ess: 35 µr	oard FR4, m	D°PAK -	_
60	+	-			+ +	+ +			-
50	\mathbb{H}								
40		\leftarrow							_
30									_
20		-							-
10		-					S _(Cu)	(cm²)	-
0	0	5	10	15	20	25	30	35	 40

Figure 7. Thermal resistance junction to ambient versus copper surface under tab (typical values)

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2 Package Information

- Epoxy meets UL94,V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m (TO-220AB)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

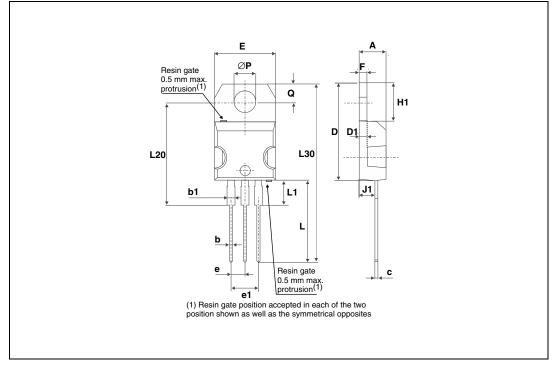


Figure 8. TO-220AB dimension definitions



	Dimensions						
Ref.	Millin	neters	Inches				
	Min.	Max.	Min.	Max.			
А	4.40	4.60	0.17	0.18			
b	0.61	0.88	0.024	0.035			
b1	1.14	1.70	0.045	0.067			
С	0.48	0.70	0.019	0.027			
D	15.25	15.75	0.60	0.62			
D1	1.27	typ.	0.05	typ.			
Е	10	10.40	0.39	0.41			
е	2.40	2.70	0.094	0.106			
e1	4.95	5.15	0.19	0.20			
F	1.23	1.32	0.048	0.052			
H1	6.20	6.60	0.24	0.26			
J1	2.40	2.72	0.094	0.107			
L	13	14	0.51	0.55			
L1	3.50	3.93	0.137	0.154			
L20	16.40 typ.		0.64 typ.				
L30	28.90	0 typ.	1.13	typ.			
ØP	3.75	3.85	0.147	0.151			
Q	2.65	2.95	0.104	0.116			

Table 5. TO-220AB dimension values

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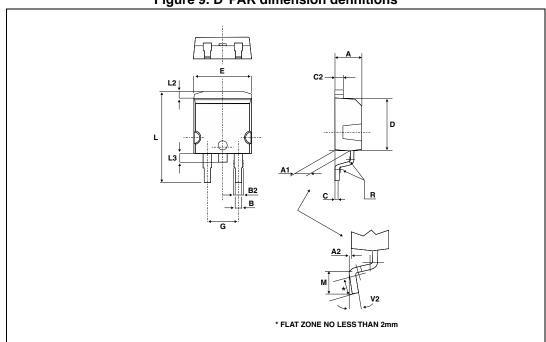
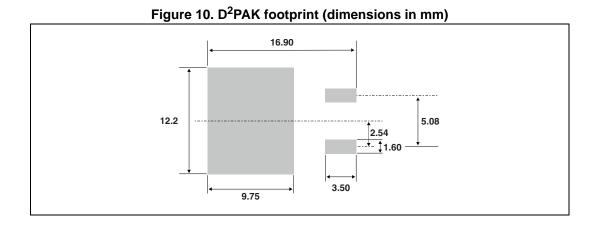


Figure 9. D²PAK dimension definitions

Table 6. D²PAK dimension values

		Dime	nsions	
Ref.	Millin	neters	Inc	hes
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.49	2.69	0.098	0.106
A2	0.03	0.23	0.001	0.009
В	0.70	0.93	0.027	0.037
B2	1.14	1.70	0.045	0.067
С	0.45	0.60	0.017	0.024
C2	1.23	1.36	0.048	0.054
D	8.95	9.35	0.352	0.368
E	10.00	10.40	0.393	0.409
G	4.88	5.28	0.192	0.208
L	15.00	15.85	0.590	0.624
L2	1.27	1.40	0.050	0.055
L3	1.30	1.75	0.051	0.069
М	2.29	2.79	0.090	0.110
R	0.40	typ.	0.010	6 typ.
V2	0°	8°	0°	8°





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3 Ordering Information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
FERD40U45CT	FERD40U45CT	TO-220AB	2.2 g	50	Tube
FERD40U45CG-TR	FERD40U45CG	D ² PAK	1.8 g	500	Tape and reel

4 Revision history

Table 8. Document revision history

Date	Revision	Description of Changes	
13-Nov-2013	1	Previous version	



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